

[0036] FIG. 8 is a plan view and a cross-sectional view illustrating a structure of the pressure-sensitive capacitive sensor according to a fourth embodiment of the invention;

[0037] FIG. 9 is a plan view and cross-sectional view illustrating a structure of the pressure-sensitive capacitive sensor in accordance with a fifth embodiment of the present invention;

[0038] FIG. 10 is a plan view and a cross-sectional view illustrating a structure of the pressure-sensitive capacitive sensor according to a sixth embodiment of the invention;

[0039] FIG. 11 is view illustrating an enlarged A portion of FIG. 10;

[0040] FIG. 12 is a cross-sectional view taken along G-G' wiring of FIG. 11;

[0041] FIG. 13 is a view for explaining a basic characteristic of a current conveyor circuit;

[0042] FIG. 14 is a circuit view illustrating a structure of a basic detecting circuit using the current conveyor circuit for signal detection;

[0043] FIG. 15 is a circuit view illustrating an example of a detecting circuit of the capacitive sensor configured to use a current conveyor circuit according to embodiments of the invention;

[0044] FIG. 16 is a circuit view illustrating another example of a detecting circuit of the capacitive sensor configured to use a current conveyor circuit according to the embodiments of the invention; and

[0045] FIG. 17 is a cross-sectional view and a plan view illustrating a schematic structure of the fingerprint reading device of the related art.

#### DESCRIPTION OF THE PREFERRED EMBODIMENT

[0046] Hereinafter, embodiments of the present invention will be described in detail with reference to the accompanying drawings. The embodiments of the invention describe the pressure-sensitive capacitive sensor applied to a fingerprint sensor. An operation principle of the pressure-sensitive capacitive sensor according to the invention will be described with reference to FIGS. 1 to 4. FIG. 1 conceptually shows an electric structure of the pressure-sensitive capacitive sensor according to the invention. In FIG. 1, the capacitive sensor 1 according to the invention includes vertical wiring lines DL1 to DLn, horizontal wiring lines SL1 to SLn, a horizontal wiring line for noise detection DD, a driving circuit 10 for supplying a driving voltage to the vertical wiring lines DL1 to DLn, and a detecting circuit 11 for detecting signal currents from the horizontal wiring lines SL1 to SLn.

[0047] In addition, a capacitance CX is a capacitance for signal-detecting formed between the vertical wiring lines and the horizontal wiring lines, and a capacitance CS is a parasitic capacitance formed between a finger and a gap where the horizontal wiring and the vertical wiring do not cross each other when the fingerprint is scanned. In addition, a capacitance CN is a parasitic capacitance formed between the finger and the horizontal wiring line for signal-detection when the fingerprint is scanned.

[0048] FIG. 2 shows a cross-sectional structure of the capacitive sensor 1. In FIG. 2, the vertical wiring lines DL1 to DLn correspond to vertical wiring lines 22, and the horizontal wiring lines SL1 to SLn correspond to horizontal wiring lines 32. In addition, the horizontal wiring line for signal-detecting is not shown in FIG. 2.

[0049] The capacitive sensor 1 has a first substrate 20 (film substrate) where a plurality of vertical wiring lines 22 is formed on one surface of a film 21, and a second substrate 30 where a plurality of horizontal wiring lines 32 is formed on a base 31, and the first and second substrates face each other with a gap interposed therebetween. The vertical wiring lines 22 and the horizontal wiring 32 are disposed in a matrix, and the horizontal wiring line for signal-detecting (not shown) is disposed not to cross the vertical wiring lines on the base 31 of the second substrate 30 where the horizontal wiring lines 32 are formed. A reference numeral 33 denotes an insulating layer.

[0050] As shown in FIG. 3, when the finger 40 comes in contact with a surface of the first substrate 20 (film substrate) formed at an upper side of the capacitive sensor 1, the first substrate 20 is deformed by an external force added according to the unevenness of the fingerprint of the finger 40, and a space between the first substrate 20 and the second substrate 30 is changed. In addition, the pressure distribution appears as the changes in the capacitance at the intersections between the vertical wiring lines and the horizontal wiring lines, and is detected by the detecting circuit 11.

[0051] In the meantime, when the finger 40 comes in contact with the first substrate, noises are flowed into the capacitive sensor 1 from a human body. FIG. 4A shows a state that the vertical wiring 22 and the horizontal wiring 32 are disposed in a matrix in the capacitive sensor 1, and FIGS. 4B and 4C are cross-sectional views taken along line A-A' of FIG. 4A.

[0052] As shown in FIG. 4B, while the finger 40 comes in contact with the film 21 of the first substrate 20, the capacitance for signal-detecting CX is formed between the vertical wiring 22 and the horizontal wiring 32, and the parasitic capacitance CS is concurrently formed between the finger 40 and the gap, that is, the area where the corresponding horizontal wiring 32 of the horizontal wiring lines 32 and the vertical wiring 22 do not cross each other.

[0053] Next, while the finger 40 is pressed onto the first substrate 20 as shown in FIG. 4C, the space between the first substrate 20 and the second substrate 30 decreases, which in turn causes the space between the vertical wiring 22 and the horizontal wiring 32 and a distance between the finger 40 and the horizontal wiring 32 to decrease as compared to a case of not pressing the finger 40 onto the first substrate 20, thereby the capacitance for signal-detecting and the parasitic capacitance increase to have values of CX' and CS', respectively. Accordingly, the amount of noises delivered from the human body further increase in a case of pressing the finger 40 onto the first substrate 20 as compared to a case of not pressing finger 40 onto the first substrate 20.

[0054] In the capacitive sensor 1 of the invention, the horizontal wiring line for noise detection DD is formed not to cross the vertical wiring on the base 31 of the second substrate 30, thereby only the noise delivered from the human body via the parasitic capacitance CN is sensed by the horizontal wiring line for noise detection.